

$V_{DSS}$	650V
$R_{DS(on)}$ (Typ.)	30m $\Omega$
$I_D^{*1}$	70A
$P_D$	262W

#### ●Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Fast reverse recovery
- 4) Easy to parallel
- 5) Simple to drive
- 6) Pb-free lead plating ; RoHS compliant

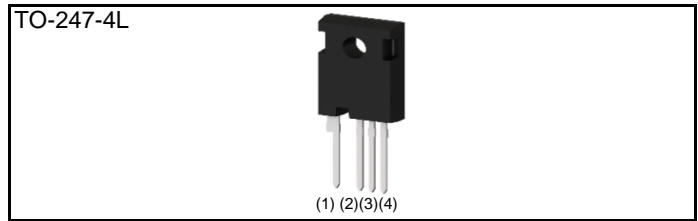
#### ●Application

- Solar inverters
- DC/DC converters
- Switch mode power supplies
- Induction heating
- Motor drives

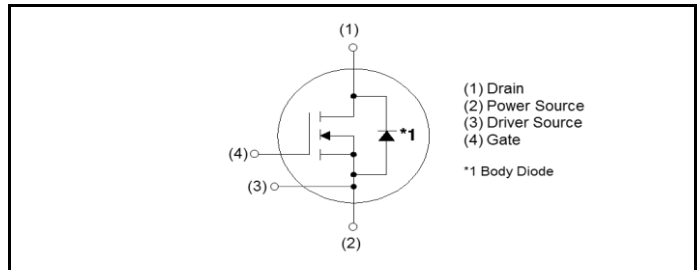
#### ●Absolute maximum ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit	
Drain - Source Voltage	$V_{DSS}$	650	V	
Continuous Drain current	$T_c = 25^\circ\text{C}$	$I_D^{*1}$	70	A
	$T_c = 100^\circ\text{C}$	$I_D^{*1}$	49	A
Pulsed Drain current	$I_{D,pulse}^{*2}$	175	A	
Gate - Source voltage (DC)	$V_{GSS}$	-4 to +22	V	
Gate - Source surge voltage ( $t_{surge} < 300\text{ns}$ )	$V_{GSS,surge}^{*3}$	-4 to +26	V	
Recommended drive voltage	$V_{GS,op}^{*4}$	0 / +18	V	
Junction temperature	$T_j$	175	$^\circ\text{C}$	
Range of storage temperature	$T_{stg}$	-55 to +175	$^\circ\text{C}$	

#### ●Outline



#### ●Inner circuit



Please note Driver Source and Power Source are not exchangeable. Their exchange might lead to malfunction.

#### ●Packaging specifications

Type	Packing	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	30
	Taping code	C14
	Marking	SCT3030AR

**●Electrical characteristics** ( $T_a = 25^\circ\text{C}$ )

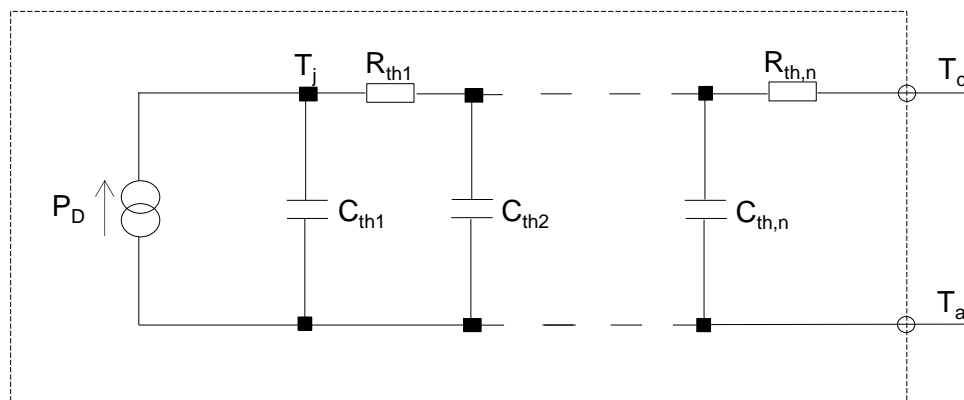
Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{V}, I_D = 1\text{mA}$ $T_j = 25^\circ\text{C}$ $T_j = -55^\circ\text{C}$	650 650	- -	- -	V
Zero Gate voltage Drain current	$I_{DSS}$	$V_{GS} = 0\text{V}, V_{DS} = 650\text{V}$ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$	- -	1 2	10 -	$\mu\text{A}$
Gate - Source leakage current	$I_{GSS+}$	$V_{GS} = +22\text{V}, V_{DS} = 0\text{V}$	-	-	100	nA
Gate - Source leakage current	$I_{GSS-}$	$V_{GS} = -4\text{V}, V_{DS} = 0\text{V}$	-	-	-100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10\text{V}, I_D = 13.3\text{mA}$	2.7	-	5.6	V
Static Drain - Source on - state resistance	$R_{DS(on)}^{*5}$	$V_{GS} = 18\text{V}, I_D = 27\text{A}$ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$	- -	30 43	39 -	m $\Omega$
Gate input resistance	$R_G$	$f = 1\text{MHz}, \text{open drain}$	-	7	-	$\Omega$

**●Thermal resistance**

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - case	$R_{thJC}$	-	0.44	0.57	$^\circ\text{C/W}$

**●Typical Transient Thermal Characteristics**

Symbol	Value	Unit	Symbol	Value	Unit
$R_{th1}$	$2.56 \times 10^{-2}$	K/W	$C_{th1}$	$1.39 \times 10^{-3}$	Ws/K
$R_{th2}$	$1.95 \times 10^{-1}$		$C_{th2}$	$1.00 \times 10^{-2}$	
$R_{th3}$	$2.20 \times 10^{-1}$		$C_{th3}$	$3.57 \times 10^{-2}$	



**●Electrical characteristics (T<sub>a</sub> = 25°C)**

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Transconductance	$g_{fs}^{*5}$	$V_{DS} = 10V, I_D = 27A$	-	9.4	-	S
Input capacitance	$C_{iss}$	$V_{GS} = 0V$	-	1526	-	pF
Output capacitance	$C_{oss}$	$V_{DS} = 500V$	-	89	-	
Reverse transfer capacitance	$C_{rss}$	$f = 1MHz$	-	42	-	
Effective output capacitance, energy related	$C_{o(er)}$	$V_{GS} = 0V$ $V_{DS} = 0V \text{ to } 300V$	-	230	-	pF
Total Gate charge	$Q_g^{*5}$	$V_{DS} = 300V$ $I_D = 27A$	-	104	-	nC
Gate - Source charge	$Q_{gs}^{*5}$	$V_{GS} = 18V$	-	19	-	
Gate - Drain charge	$Q_{gd}^{*5}$	See Fig. 1-1.	-	55	-	
Turn - on delay time	$t_{d(on)}^{*5}$	$V_{DS} = 400V$ $I_D = 27A$	-	7	-	ns
Rise time	$t_r^{*5}$	$V_{GS} = 0V/+18V$	-	22	-	
Turn - off delay time	$t_{d(off)}^{*5}$	$R_G = 0\Omega, L = 750\mu H$ $L_\sigma = 50nH, C_\sigma = 10pF$	-	27	-	
Fall time	$t_f^{*5}$	See Fig. 2-1, 2-2, 2-3.	-	21	-	
Turn - on switching loss	$E_{on}^{*5}$	$E_{on}$ includes diode reverse recovery.	-	159	-	$\mu J$
Turn - off switching loss	$E_{off}^{*5}$		-	87	-	

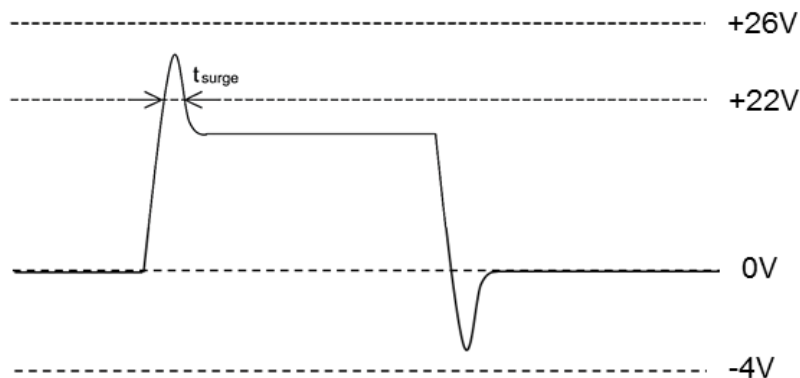
**●Body diode electrical characteristics (Source-Drain) ( $T_a = 25^\circ\text{C}$ )**

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Body diode continuous, forward current	$I_S$ *1	$T_c = 25^\circ\text{C}$	-	-	70	A
Body diode direct current, pulsed	$I_{SM}$ *2		-	-	175	A
Forward voltage	$V_{SD}$ *5	$V_{GS} = 0\text{V}, I_D = 27\text{A}$	-	3.2	-	V
Reverse recovery time	$t_{rr}$ *5	$I_F = 27\text{A}$ $V_R = 400\text{V}$	-	28	-	ns
Reverse recovery charge	$Q_{rr}$ *5	$di/dt = 2500\text{A}/\mu\text{s}$	-	702	-	nC
Peak reverse recovery current	$I_{rrm}$ *5	$L_\sigma = 50\text{nH}, C_\sigma = 10\text{pF}$ See Fig. 3-1, 3-2.	-	40	-	A

\*1 Limited by maximum temperature allowed.

\*2  $P_W \leq 10\mu\text{s}$ , Duty cycle  $\leq 1\%$

\*3 Example of acceptable  $V_{GS}$  waveform



Please note especially when using driver source that  $V_{GSS\_surge}$  must be in the range of absolute maximum rating.

\*4 Please be advised not to use SiC-MOSFETs with  $V_{GS}$  below 13V as doing so may cause thermal runaway.

\*5 Pulsed

●Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

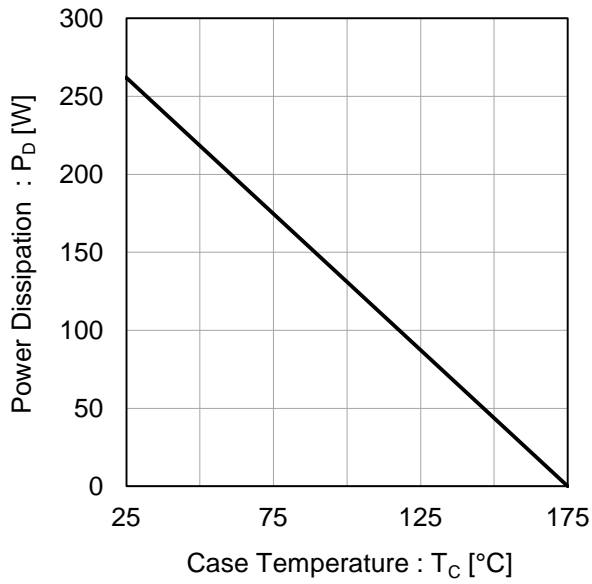


Fig.2 Maximum Safe Operating Area

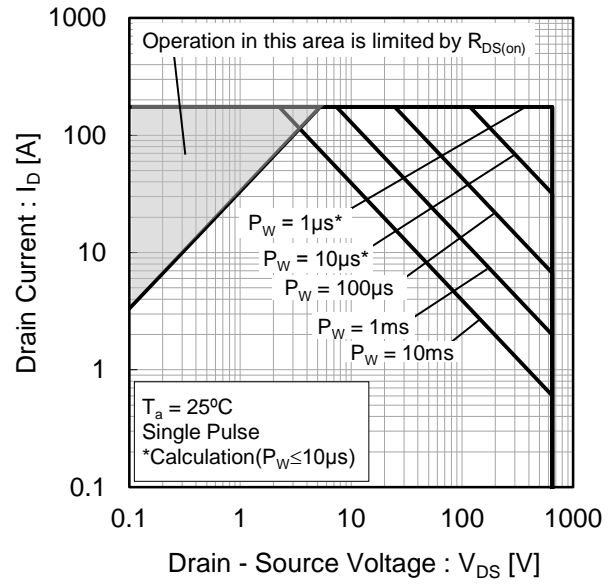
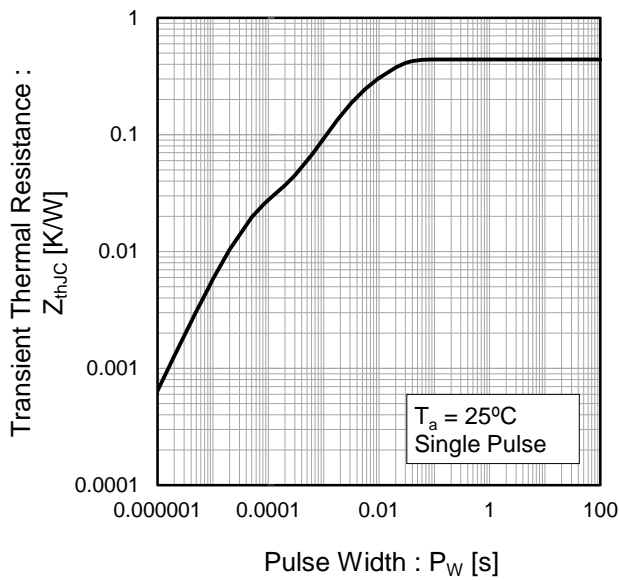


Fig.3 Typical Transient Thermal Resistance vs. Pulse Width



●Electrical characteristic curves

Fig.4 Typical Output Characteristics(I)

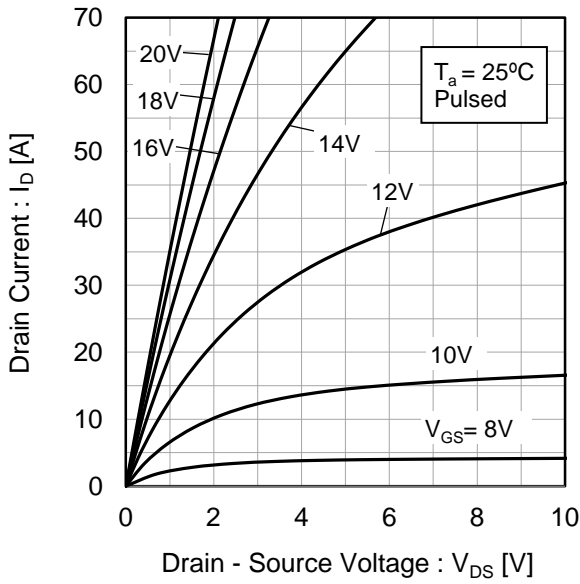


Fig.5 Typical Output Characteristics(II)

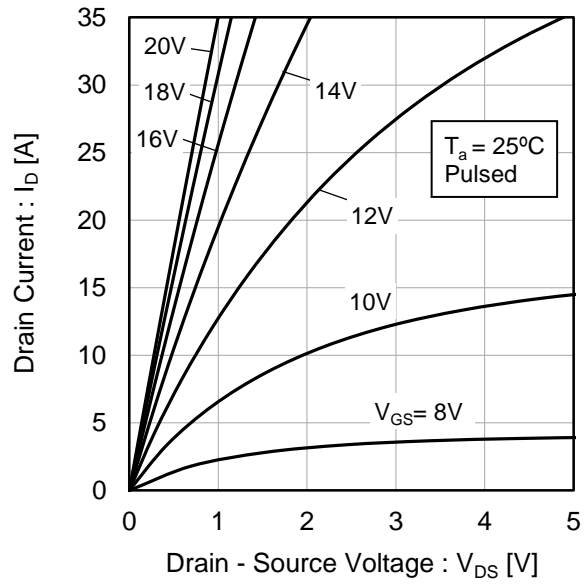
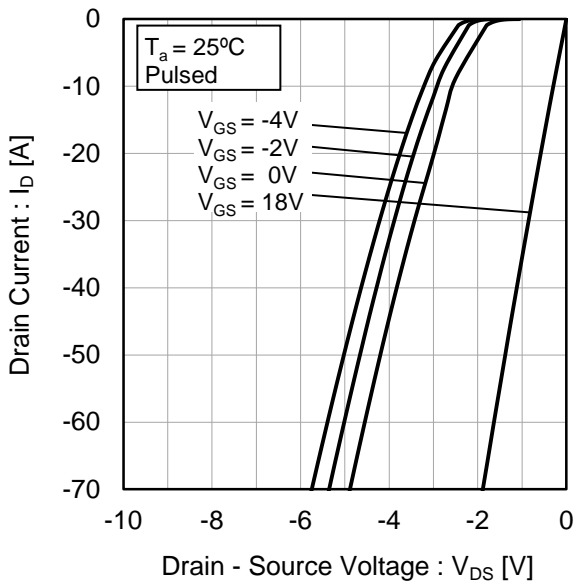


Fig.6  $T_j = 25^\circ\text{C}$  3rd Quadrant Characteristics



●Electrical characteristic curves

Fig.7  $T_j = 150^\circ\text{C}$  Typical Output Characteristics(I)

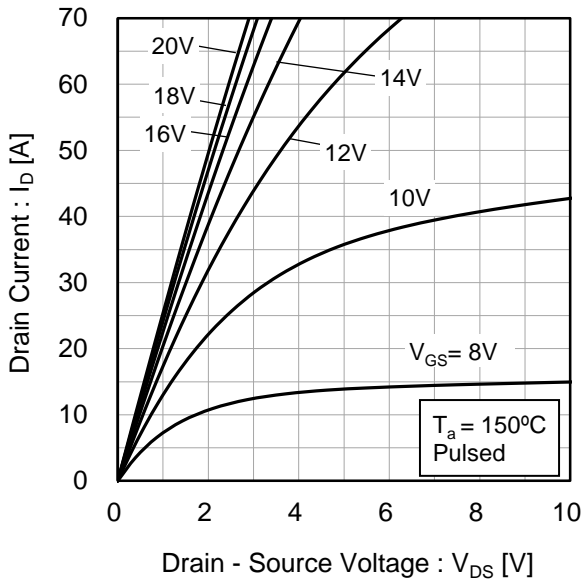


Fig.8  $T_j = 150^\circ\text{C}$  Typical Output Characteristics(II)

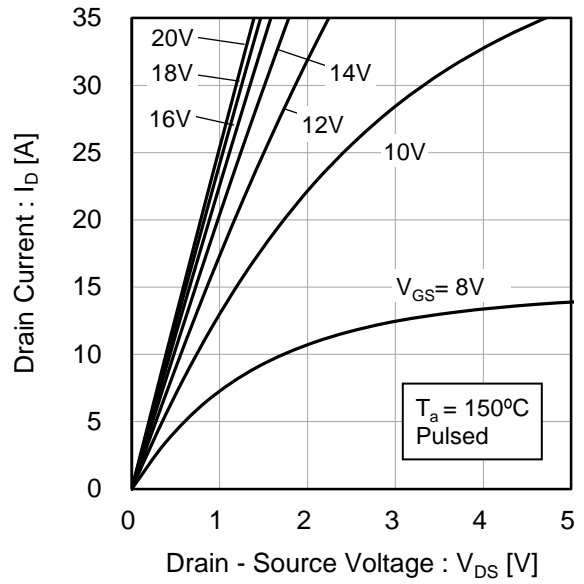


Fig.9  $T_j = 150^\circ\text{C}$  3rd Quadrant Characteristics

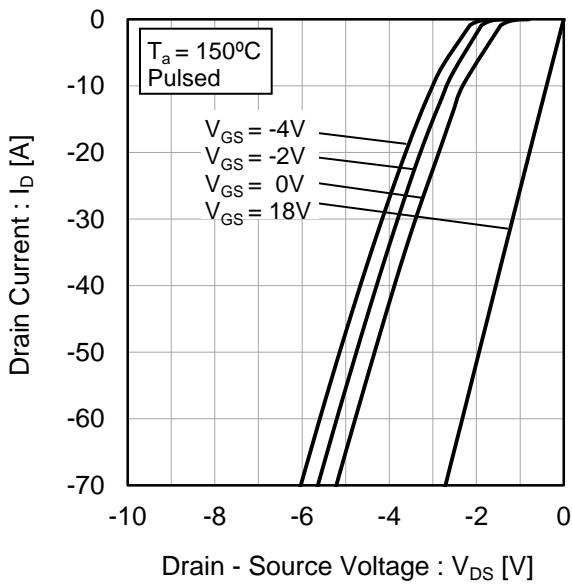
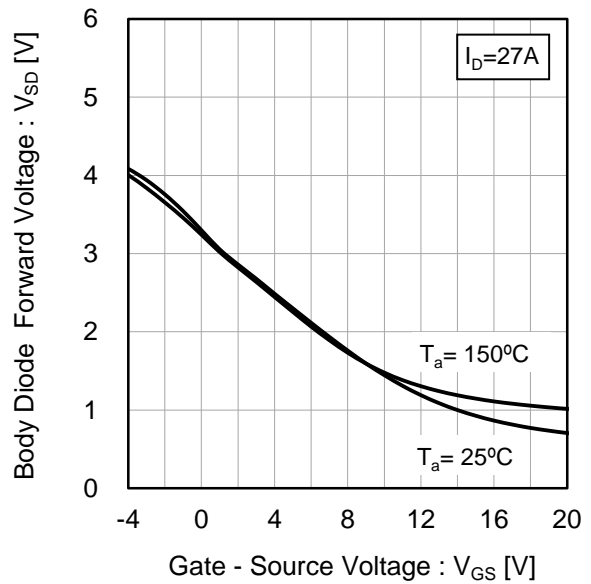


Fig.10 Body Diode Forward Voltage vs. Gate - Source Voltage



●Electrical characteristic curves

Fig.11 Typical Transfer Characteristics (I)

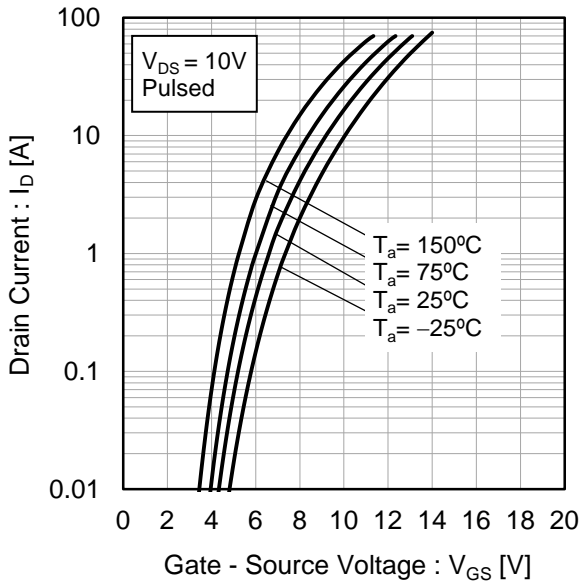


Fig.12 Typical Transfer Characteristics (II)

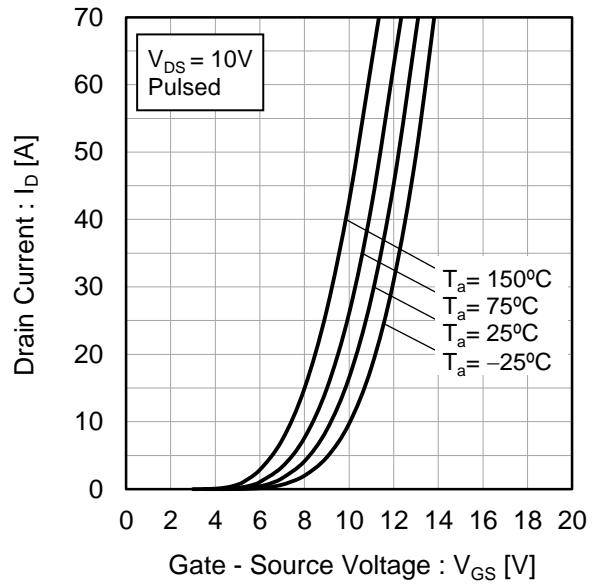


Fig.13 Gate Threshold Voltage vs. Junction Temperature

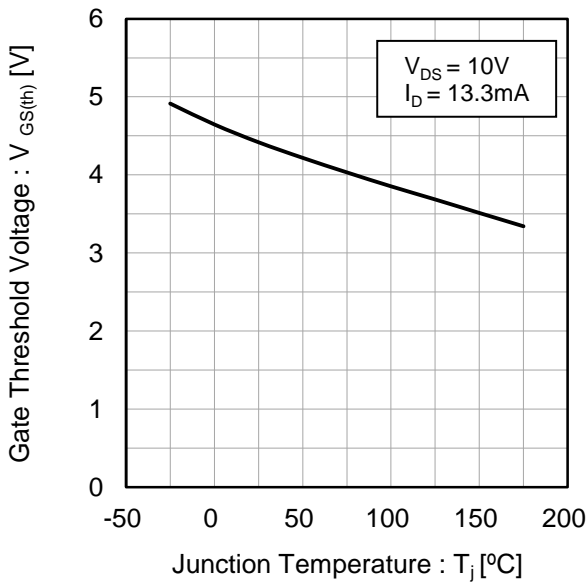
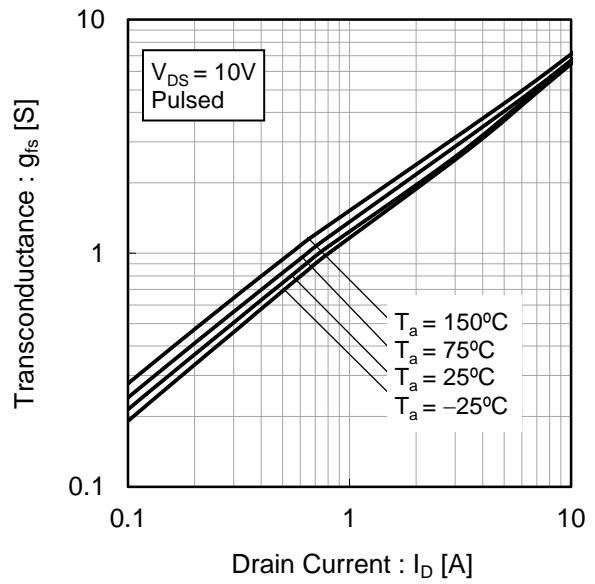


Fig.14 Transconductance vs. Drain Current





●Electrical characteristic curves

Fig.15 Static Drain - Source On - State Resistance vs. Gate - Source Voltage

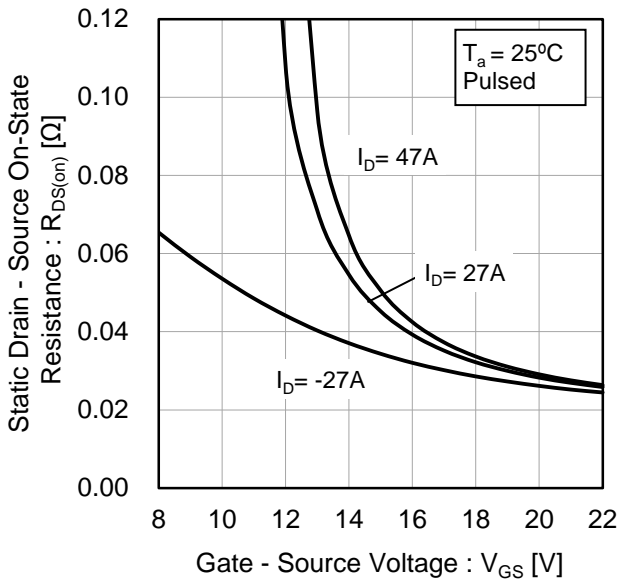


Fig.16 Static Drain - Source On - State Resistance vs. Junction Temperature

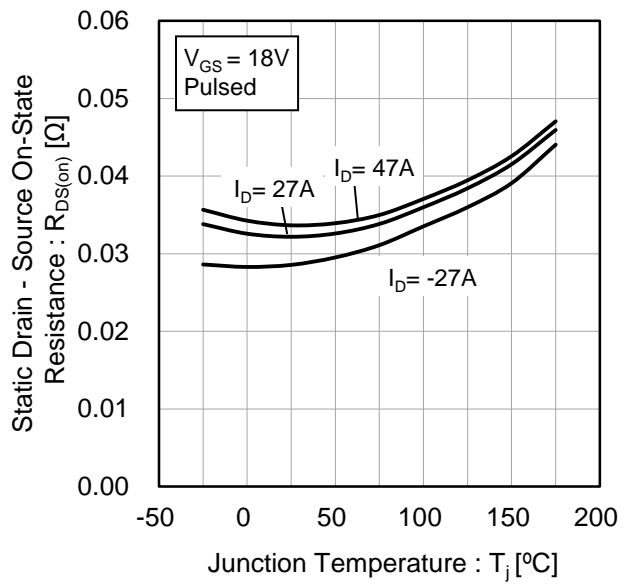


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current

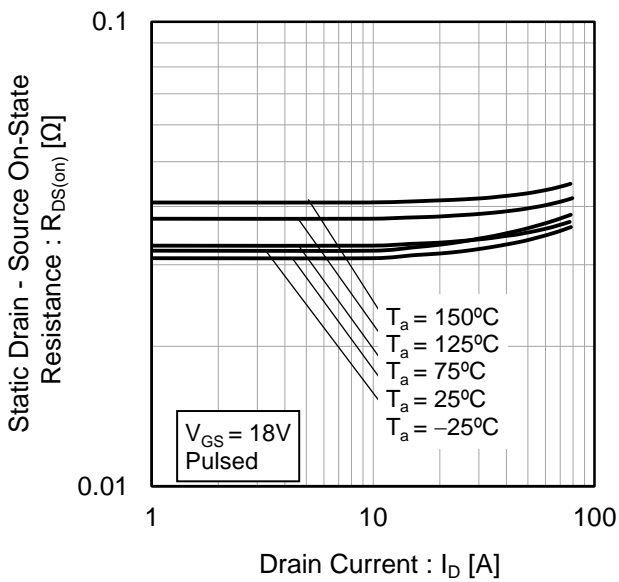
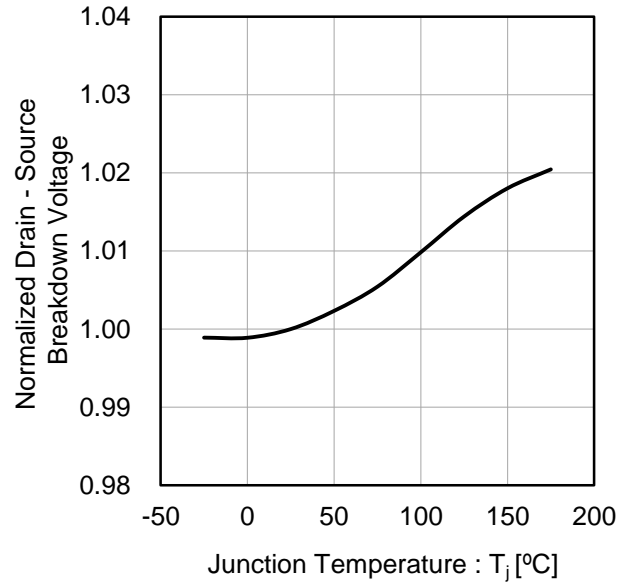


Fig.18 Normalized Drain - Source Breakdown Voltage vs. Junction Temperature



●Electrical characteristic curves

Fig.19 Typical Capacitance vs. Drain - Source Voltage

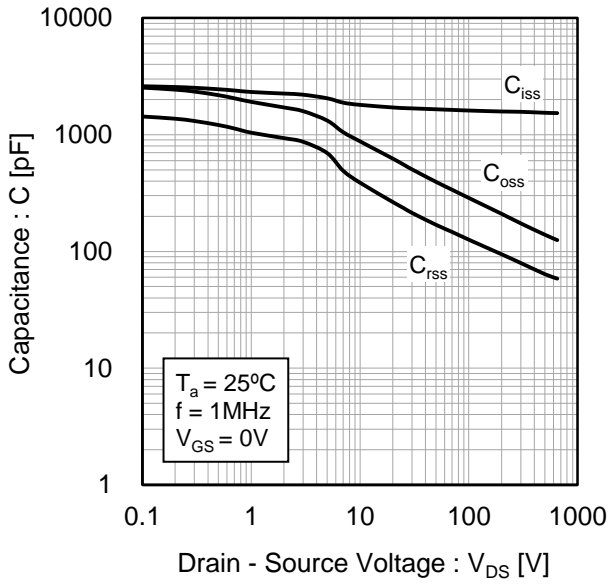


Fig.20 C<sub>oss</sub> Stored Energy

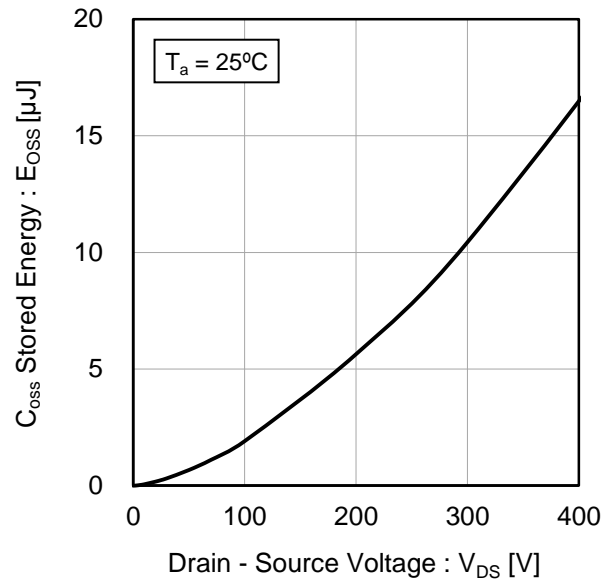
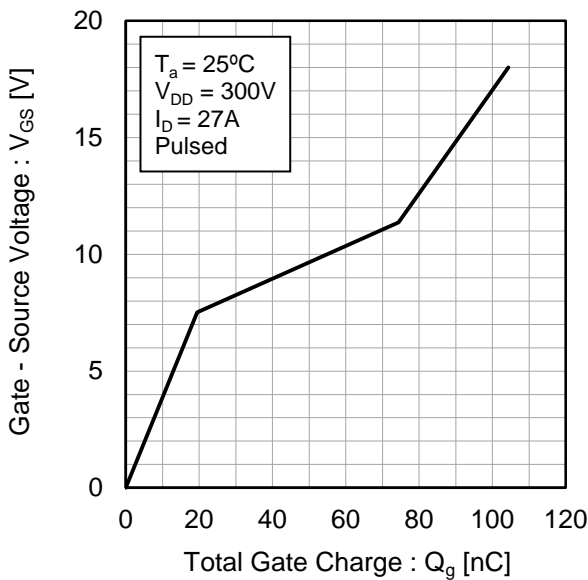
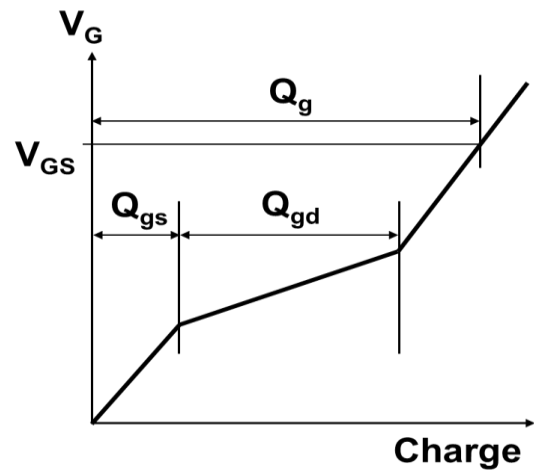


Fig.21 Dynamic Input Characteristics



\*Gate Charge Waveform



●Electrical characteristic curves

Fig.22 Typical Switching Time vs. External Gate Resistance

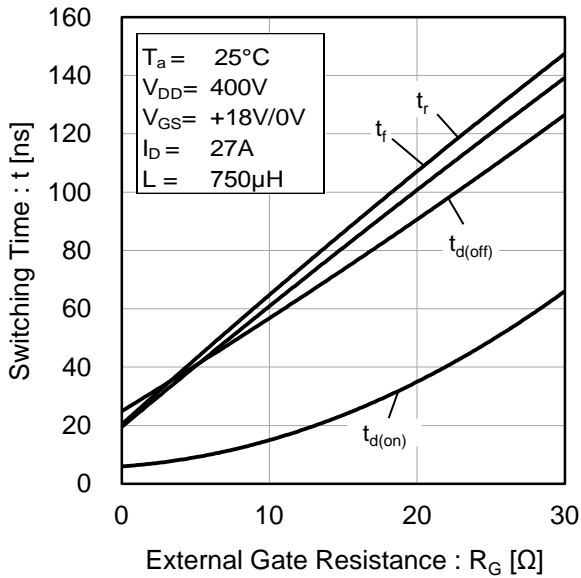


Fig.23 Typical Switching Loss vs. Drain - Source Voltage

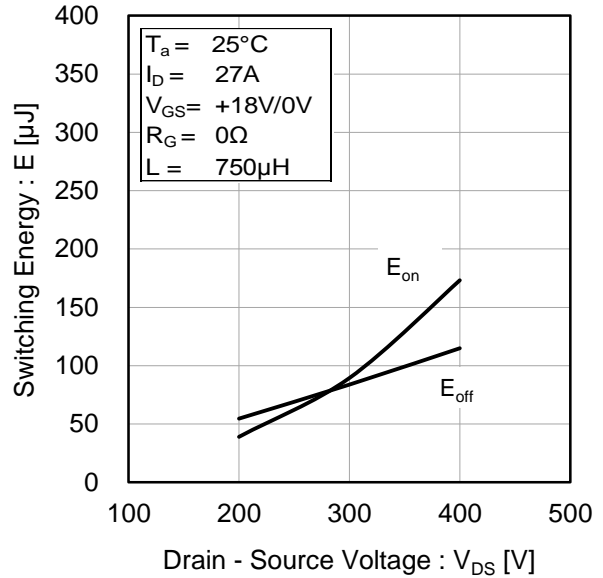


Fig.24 Typical Switching Loss vs. Drain Current

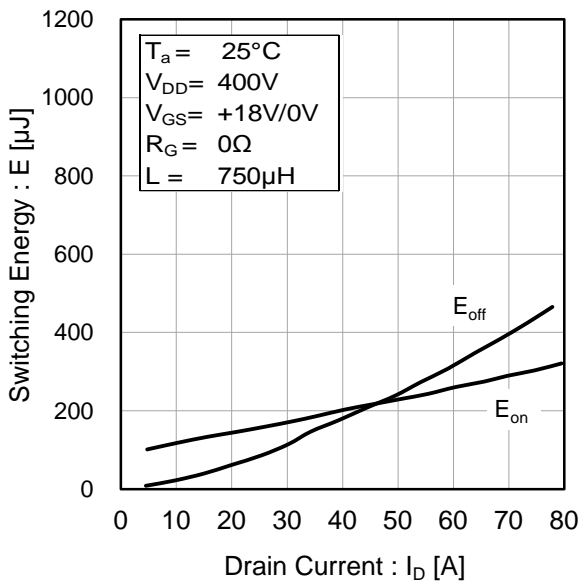
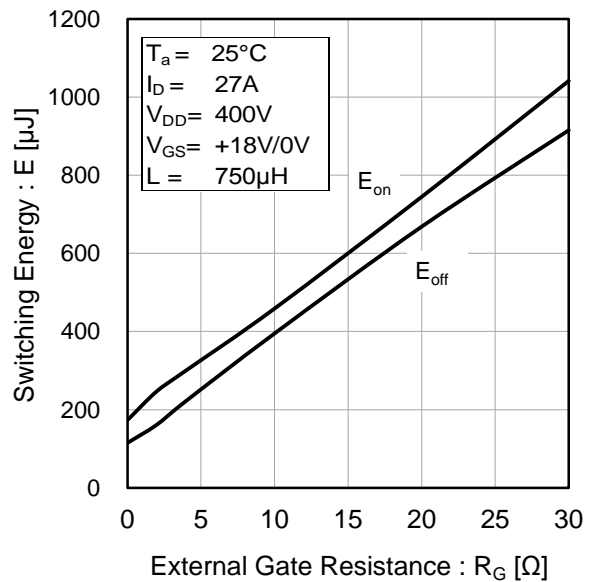


Fig.25 Typical Switching Loss vs. External Gate Resistance



● Measurement circuits and waveforms

Fig.1-1 Gate Charge Measurement Circuit

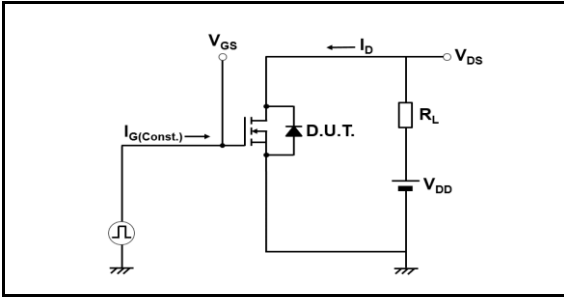


Fig.2-1 Switching Characteristics Measurement Circuit

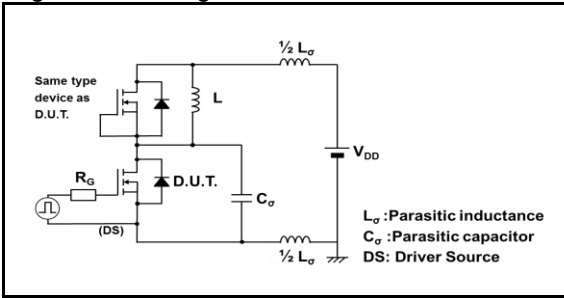


Fig.2-2 Waveforms for Switching Time

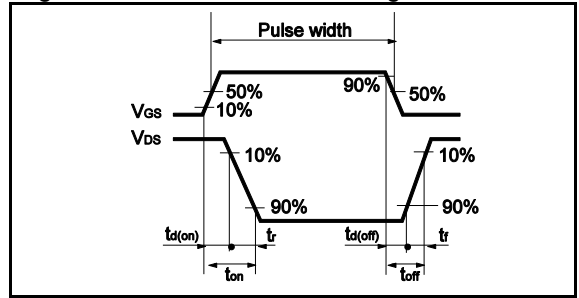


Fig.2-3 Waveforms for Switching Energy Loss

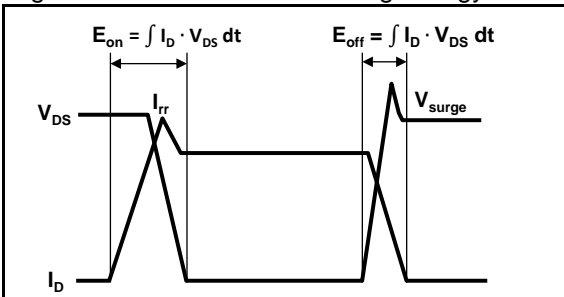


Fig.3-1 Reverse Recovery Time Measurement Circuit

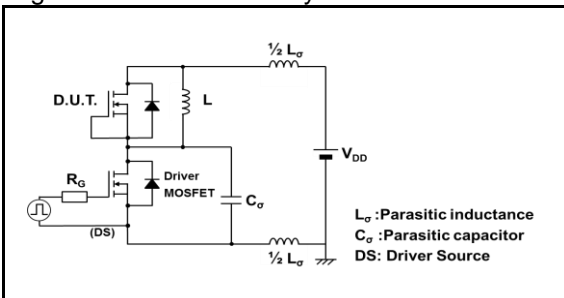
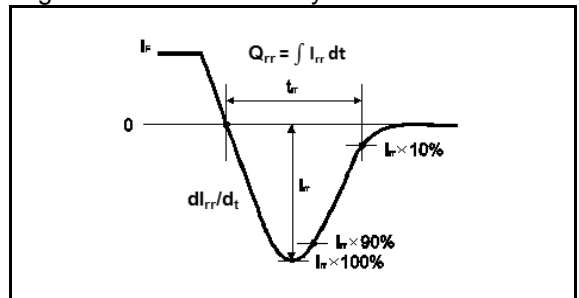


Fig.3-2 Reverse Recovery Waveform



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SCT3030AR - Web Page

Part Number	SCT3030AR
Package	TO-247-4L
Unit Quantity	450
Minimum Package Quantity	30
Packing Type	Tube
Constitution Materials List	inquiry
RoHS	Yes